NSN 5962-01-359-5490

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-359-5490

Body Length:

Between 0.540 inches and 0.560 inches

Body Width:

Between 0.442 inches and 0.458 inches

Maximum Power Dissipation Rating:

1.0 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

W/enable and w/disable and w/clear and monolithic

Inclosure Material:

Ceramic

Inclosure Configuration:

Leadless flat pack

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Input Circuit Pattern:

26 input

Case Outline Source And Designator:

C-12 mil-m-38510

Current Rating Per Characteristic:

80.00 milliamperes reverse current, dc absolute

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.3 volts power source and 6.25 volts power source

Capitance Rating Per Characteristic:

10.00 input picofarads and 10.00 output picofarads

Time Rating Per Chacteristic:

250.00 nanoseconds access

Memory Device Type:

Eeprom

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

32 leadless

Shelf Life:

N/a

Unit Of Measure:

NSN 5962-01-359-5490

Memory Microcircuit - Page 2 of 2

Demilitarization:

Yes - demil/mli

Fiig:

A458a0

